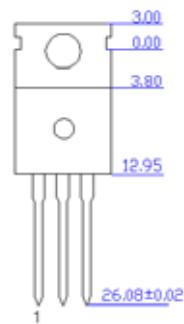


STANDARD

Passivated sensitive gate triacs in plastic envelope, intended for use in general purpose bi-directional switching and phase control applications, where high sensitivity is required in all four quadrants.

△ ABSOLUTE MAXIMUM RATINGS (TA=25°C)

Characteristic	Symbol	Rating	Unit
Repetitive Peak off-state voltage	V _{DRM}	700	V
RMS on-state current	I _T (RMS)	4	A
Non-repetitive peak on-state current	I _{TSM}	40	A
Peak gate power	P _{GM}	5	W
Peak gate current	I _{GM}	2	A
Junction Temperature	T _J	125	
Storage Temperature	T _{STG}	-40-150	

TO-220AB

△ ELECTRICAL CHARACTERISTICS (TA=25°C)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Repetitive Peak off-state voltage	V _{DRM}		700			V
Gate trigger current	I _{GT}	V _D =12V; RL=33Ω T2+ G+		2.5	10	mA
		V _D =12V; RL=33Ω T2+ G-		4.0	10	mA
		V _D =12V; RL=33Ω T2- G+		5.0	10	mA
		V _D =12V; RL=33Ω T2- G-		11	25	mA
Base-Emitter Saturation Voltage	I _L	IG =1.2IGT			40	mA
Gate trigger voltage	V _{GT}	V _D =12V; RL=33Ω			1.5	V
Holding current	I _H	I _T =100mA gate open			25	mA
Off-state leakage current	I _D	V _D = V _{DRM(MAX)} ; Tj=125 °C		0.1	0.5	mA
On-state voltage	V _T	I _T =5A		1.4	1.7	V
Gate controlled turn-on time	T _{GTR}	V _D = V _{DRM(MAX)} ; I _G =40 DI _G /dt=5A/us		2		us

PRODUCT SELECTOR

Part Number	Voltage	Sensitivity	Type	Package
BTB04-600SAP	600V	10 mA	Standard	TO-220AB

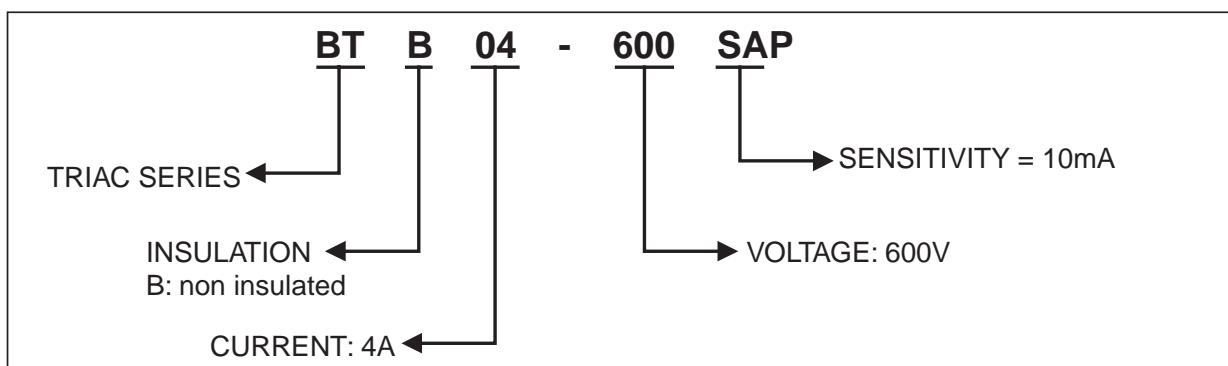
ORDERING INFORMATION


Fig. 1: Maximum power dissipation versus RMS on-state current

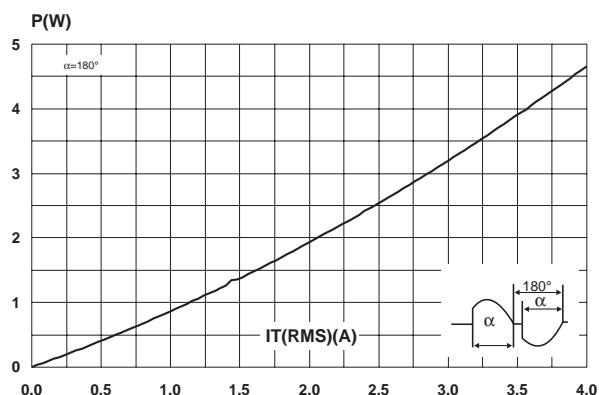


Fig. 2: RMS on-state current versus case temperature.

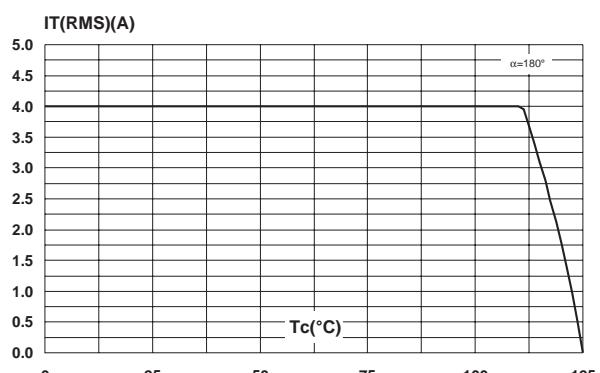


Fig. 3: Relative variation of thermal impedance versus pulse duration.

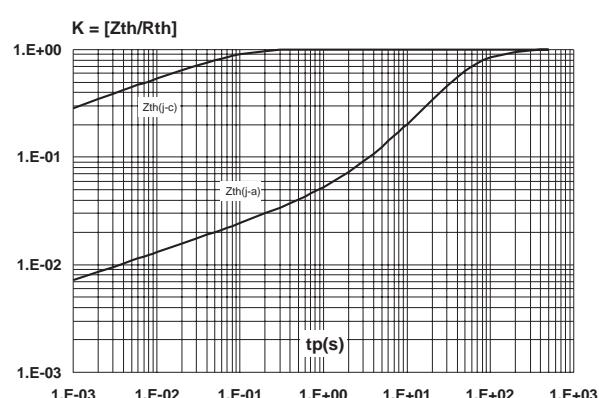


Fig. 4: On-state characteristics (maximum values)

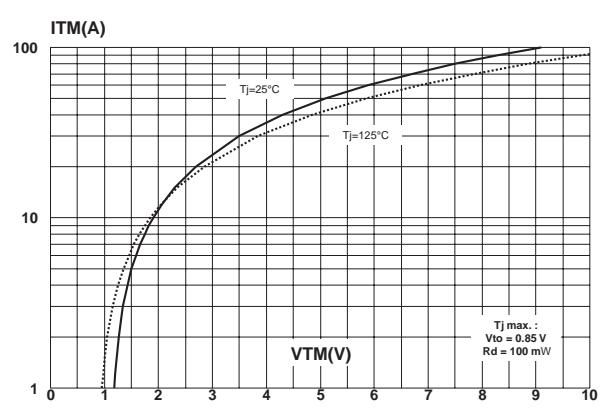


Fig. 5: Surge peak on-state current versus number of cycles.

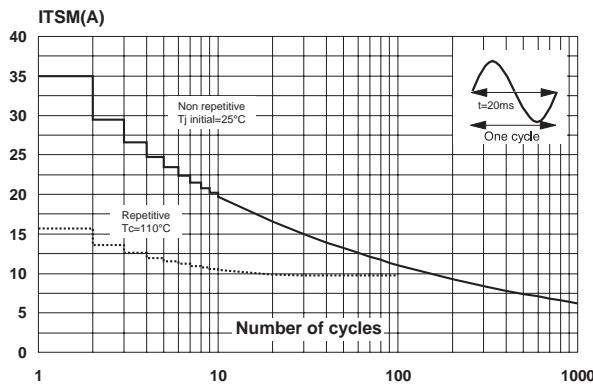


Fig. 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

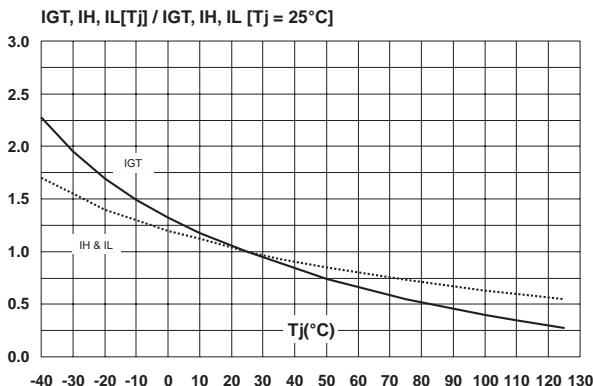


Fig. 9: Relative variation of critical rate of decrease of main current versus junction temperature.

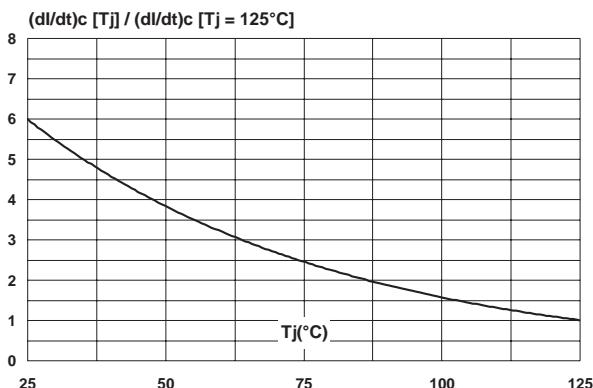


Fig. 6: Non repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 10\text{ms}$, and corresponding value of I^2t .

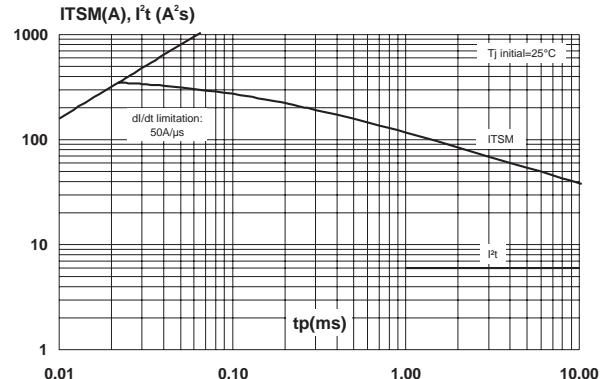


Fig. 8: Relative variation of critical rate of decrease of main current versus reapplied dV/dt (typical values).

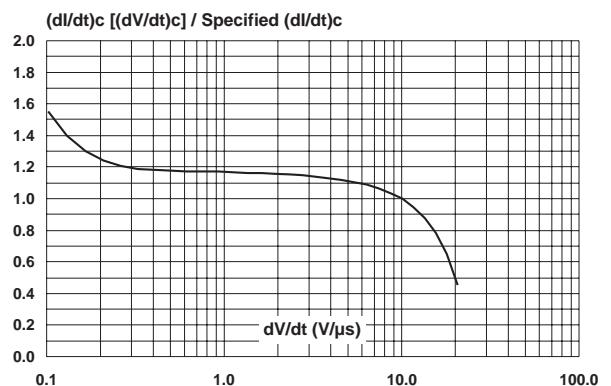
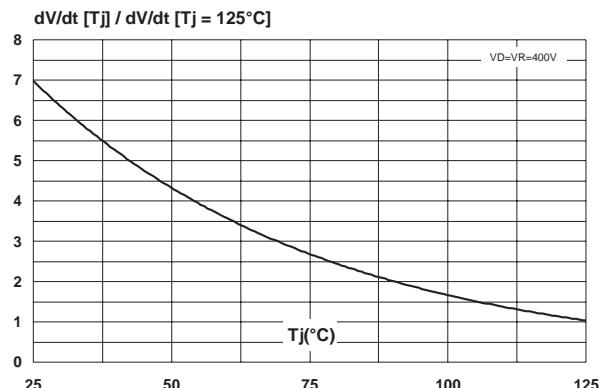


Fig. 10: Relative variation of static dV/dt immunity versus junction temperature.



PACKAGE MECHANICAL DATA

TO-220AB (Plastic)

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

OTHER INFORMATION

Ordering type	Marking	Package	Weight	Base qty	Packing mode
BTB04-600SAP	BTB04-600SAP	TO-220AB	2.3 g	50	Tube